RoHS

COMPLIANT

Vishay Semiconductors

Single Phase Bridge Rectifier, 25 A, 35 A



www.vishay.com

D-34

| PRIMARY CHARACTERISTICS | | | |
|-------------------------|---------------------|--|--|
| Io | 25 A, 35 A | | |
| V _{RRM} | 200 V to 1200 V | | |
| Package | D-34 | | |
| Circuit configuration | Single phase bridge | | |

FEATURES

- Universal, 3 way terminals: push-on, wrap around, or solder
- High thermal conductivity package, electrically insulated case
- Center hole fixing
- Excellent power/volume ratio
- UL E300359 approved 📢
- Nickel plated terminals solderable using lead (Pb)-free solder; solder alloy Sn/Ag/Cu (SAC305); solder temperature 260 °C to 275 °C
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

A range of extremely compact, encapsulated single phase bridge rectifiers offering efficient and reliable operation. They are intended for use in general purpose and instrumentation applications.

| MAJOR RATINGS AND CHARACTERISTICS | | | | |
|-----------------------------------|-----------------|-----------------|-----------------|------------------|
| SYMBOL | CHARACTERISTICS | VALUES 26MBA | VALUES 36MBA | UNITS |
| | | 25 | 35 | A |
| I _O | T _C | 65 | 60 | °C |
| I _{FSM} | 50 Hz | 400 | 475 | • |
| | 60 Hz | 420 | 500 | A |
| l ² t | 50 Hz | 790 | 1130 | A ² s |
| 1-1 | 60 Hz | 725 | 1030 | A-5 |
| V _{RRM} | Range | 200 to 1200 | | V |
| TJ | | -55 to +150 | | °C |

ELECTRICAL SPECIFICATIONS

| VOLTAGE RATINGS | | | | | |
|-----------------|-----------------|---|---|---|--|
| TYPE NUMBER | VOLTAGE CODE | V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V | V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V | I _{RRM} MAXIMUM AT T _J MAXIMUM | |
| 26MBA, 36MBA | 05 | 50 | 75 | | |
| | 06 | 60 | 100 | | |
| | 10 | 100 | 150 | | |
| | 20 | 200 | 275 | | |
| | 40 | 400 | 500 | 2 | |
| | 60 | 600 | 725 | | |
| | 80 | 800 | 900 | | |
| | 100 | 1000 | 1100 | | |
| | 120 | 1200 | 1300 | | |

 Revision: 15-Jan-2019
 1
 Document Number: 93563

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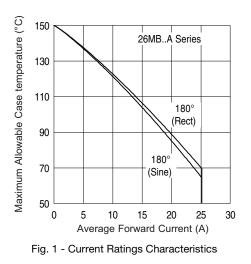


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| FORWARD CONDUCTION | | | | | | | |
|---|---------------------|--|------------------------|---------------------|-----------------|-----------------|------------------|
| PARAMETER | SYMBOL | | TEST CONDITI | ONS | VALUES 26MBA | VALUES 36MBA | UNITS |
| | | Resistive or inductive load | | 25 | 35 | А | |
| Maximum DC output current at case temperature | Ι _Ο | Capacitive loa | ad | | 20 | 28 | ~ |
| | | | | | 65 | 60 | °C |
| Maximum peak, one-cycle non-repetitive forward current | | t = 10 ms | No voltage | | 400 | 475 | A |
| | I | t = 8.3 ms | reapplied | | 420 | 500 | |
| | I _{FSM} | t = 10 ms | 100 % V _{RRM} | | 335 | 400 | |
| | | t = 8.3 ms | reapplied | Initial | 350 | 420 | |
| Maximum I ² t for fusing | l ² t | t = 10 ms | No voltage | $T_J = T_J maximum$ | 790 | 1130 | A ² s |
| | | t = 8.3 ms | reapplied | | 725 | 1030 | |
| | | t = 10 ms | 100 % V _{RRM} | | 560 | 800 | |
| | | t = 8.3 ms | reapplied | | 512 | 730 | |
| Maximum I ² √t for fusing | l²√t | I^2t for time $t_x = I_2 \sqrt{\tau} \; x \; \sqrt{\tau_x}; \; 0.1 \leq t_x \leq 10 \; \text{ms}, \; V_{\text{RRM}} = 0 \; \text{V}$ | | 5.6 | 11.3 | kA²√s | |
| Low level value of threshold voltage | V _{F(TO)1} | (16.7 % x π x $I_{F(AV)} < I < \pi$ x $I_{F(AV)}$), T _J maximum | | 0.76 | 0.79 | v | |
| High level value of threshold voltage | V _{F(TO)2} | $(I > \pi \times I_{F(AV)}), T_J$ maximum | | 0.92 | 0.96 | v | |
| Low level forward slope resistance | r _{t1} | (16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), T _J maximum | | 6.8 | 5.8 | mΩ | |
| High level forward slope resistance | r _{t2} | $(I > \pi \times I_{F(AV)}), T_J$ maximum | | 5.0 | 4.5 | 1112 | |
| Maximum forward voltage drop | V _{FM} | $ \begin{array}{l} T_J = 25 \ ^{\circ}\text{C}, \ t_p = 400 \ \mu\text{s}, \ I_{FM} = 40 \ A_{pk} \ (26\text{MB}), \\ I_{FM} = 55 \ A_{pk} \ (36\text{MB}) \end{array} $ | | 1.11 | 1.14 | V | |
| Maximum DC reverse current | I _{RRM} | $T_J = 25 \text{ °C}$, per diode at V_{RRM} | | 1 | 0 | μA | |
| RMS isolation voltage base plate | VINS | f = 50 Hz, t = 1 s | | 27 | 00 | V | |

| THERMAL AND MECHANICAL SPECIFICATIONS | | | | | |
|--|-----------------------------------|---|------------------|------------------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES 26MB-A | VALUES 36MB-A | UNITS |
| Junction and storage temperature range | T _J , T _{Stg} | | -55 to | o 150 | °C |
| Maximum thermal resistance junction to case per bridge | R _{thJC} | | 1.7 | 1.2 | |
| Maximum thermal resistance, case to heatsink | R _{thCS} | Mounting surface, smooth, flat, and greased | 0.2 | | K/W |
| Approximate weight | | | 20 | | g |
| Mounting torque ± 10 % | | Bridge to heatsink | 2 | 0 | Nm |



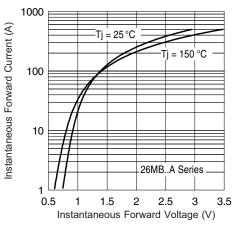


Fig. 2 - Forward Voltage Drop Characteristics Maximum Allowable Ambient Temperature

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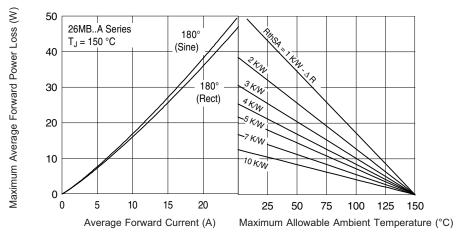
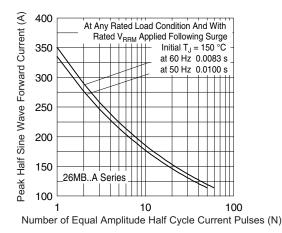


Fig. 3 - Total Power Loss Characteristics



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Fig. 4 - Maximum Non-Repetitive Surge Current

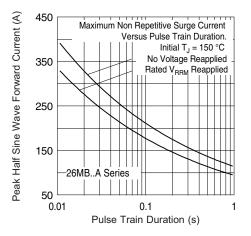


Fig. 5 - Maximum Non-Repetitive Surge Current

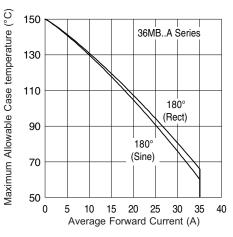


Fig. 6 - Current Ratings Characteristics

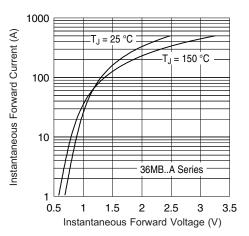


Fig. 7 - Forward Voltage Drop Characteristics

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VS-MB Series

HAY. www.vishay.com

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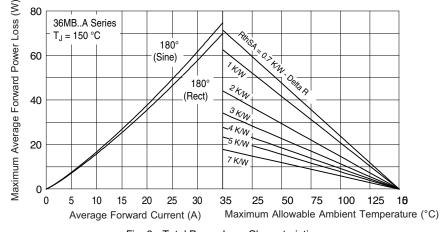


Fig. 8 - Total Power Loss Characteristics

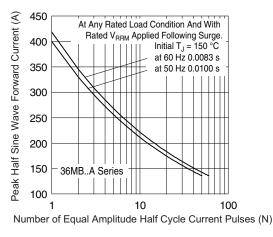


Fig. 9 - Maximum Non-Repetitive Surge Current

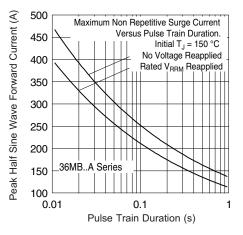


Fig. 10 - Maximum Non-Repetitive Surge Current

ORDERING INFORMATION TABLE

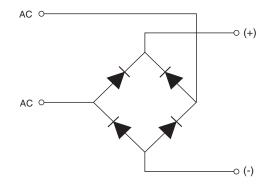
VS-36 MB 120 **Device code** Α 2 3 4 5 1 Vishay Semiconductors product 1 26 = 25 A (average) 2 Current rating code 36 = 35 A (average) 3 Circuit configuration: MB = Single phase european coding Voltage code x $10 = V_{RRM}$ 4 5 Diode bridge rectifier: A = 26 MB, 36 MB series



VS-MB Series

Vishay Semiconductors

CIRCUIT CONFIGURATION



| LINKS TO RELATED DOCUMENTS | | | |
|----------------------------|--------------------------|--|--|
| Dimensions | www.vishay.com/doc?95326 | | |

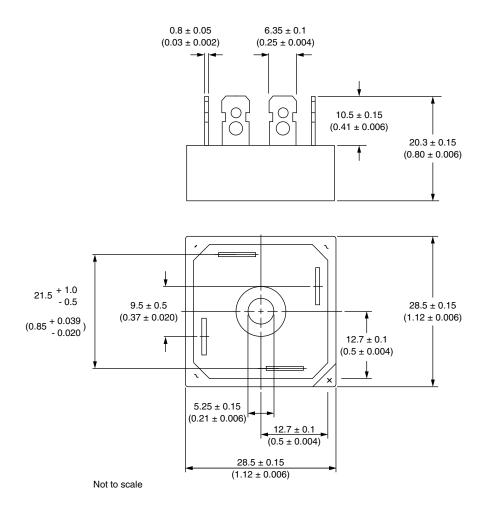


Outline Dimensions

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D-34

DIMENSIONS in millimeters (inches)



Suggested plugging force: 200 N max; axially applied to fast-on terminals



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